Unit: mm

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSII)

SSM3J14T

Power Management Switch DC-DC Converters

- Suitable for high-density mounting due to compact package
- Low on Resistance: R_{on} = 145 m Ω (max) (@VGS = -4.5 V) : R_{on} = 85 m Ω (max) (@VGS = -10 V)
- High-speed switching

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol		Rating	Unit	
Drain-Source voltage		V_{DS}		-30	V	
Gate-Source voltage		V _{GSS}		±20	V	
Drain current	DC		ΙD	-2.7	А	
	Pulse		I _{DP} (Note 2)	-5.4		
Drain power dissipation		P _D	t = 10 s	1.25	W	
			(Note 1)	0.7		
Channel temperature		T _{ch}		150	°C	
Storage temperature range		T _{stg}		-55 to 150	°C	

Note 1: Mounted on FR4 board

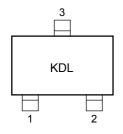
 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu pad: } 645 \text{ mm}^2)$

Note 2: The pulse width limited by maximum channel temperature.

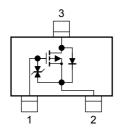
2.8:02 1.6:03 1.6:03 1. GATE 2. SOURCE 3. DRAIN TSM JEDEC — JEITA — TOSHIBA 2-3S1A

Weight: 10 mg (typ.)

Marking



Equivalent Circuit



Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

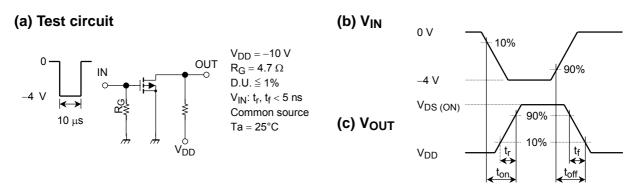
The Channel-to-Ambient thermal resistance R_{th} (ch-a) and the drain power dissipation P_D vary according to the board material, board area, board thickness and pad area, and are also affected by the environment in which the product is used. When using this device, please take heat dissipation fully into account

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage current		I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	_	_	±1	μΑ	
Drain-source breakdown voltage		V (BR) DSS	$I_D = -1 \text{ mA}, V_{GS} = 0$	-30	_	_	V	
		V _{(BR)DSX}	$I_D = -1 \text{ mA}, V_{GS} = 20 \text{ V}$	-15	_	_	V	
Drain cut-off current		I _{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0$	_	_	-1	μА	
Gate threshold voltage		V_{th}	$V_{DS} = -5 \text{ V}, I_D = -0.1 \text{ mA}$	-0.8	_	-2.0	V	
Forward transfer admittance		Y _{fs}	$V_{DS} = -5 \text{ V}, I_D = -1.35 \text{ A}$ (Note 3)	2.0	_	_	S	
Drain-source on resistance		R _{DS} (ON)	$I_D = -1.35 \text{ A}, V_{GS} = -10 \text{ V}$ (Note 3)	_	63	85	mΩ	
			$I_D = -1.35 \text{ A}, V_{GS} = -4.5 \text{ V}$ (Note 3)	_	106	145		
			$I_D = -1.35 \text{ A}, V_{GS} = -4.0 \text{ V}$ (Note 3)	_	120	170		
Input capacitance		C _{iss}	$V_{DS} = -15 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	413	_	pF	
Reverse transfer capacitance		C _{rss}	$V_{DS} = -15 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	77	_	pF	
Output capacitance		C _{oss}	$V_{DS} = -15 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	113	_	pF	
Switching time	Turn-on time	t _{on}	$V_{DD} = -15 \text{ V}, I_D = -1 \text{ A}$	_	29	_	ns	
	Turn-off time	t _{off}	$V_{GS} = 0 \sim -4 \text{ V}, R_G = 10 \Omega$	_	29	_		

Note 3: Pulse test

Switching Time Test Circuit



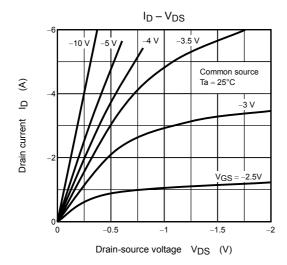
Precaution

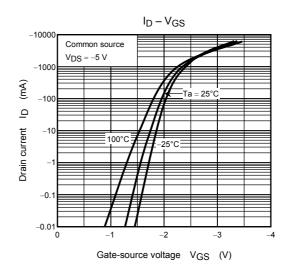
 $V_{th} \ can \ be \ expressed \ as \ voltage \ between \ gate \ and \ source \ when \ low \ operating \ current \ value \ is \ I_D = -100 \ \mu A$ for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} .

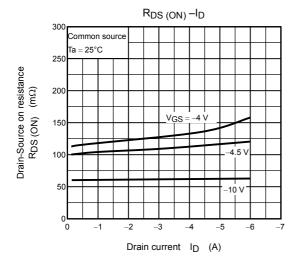
(relationship can be established as follows: $V_{GS}\left(_{off}\right) < V_{th} < V_{GS}\left(_{on}\right)$

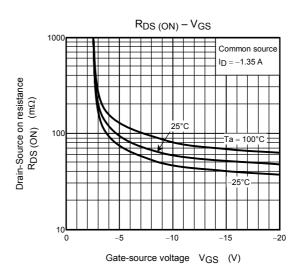
Please take this into consideration for using the device.

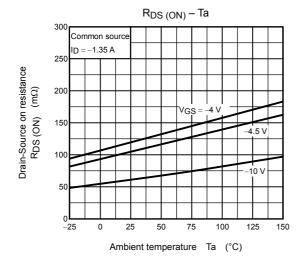
 V_{GS} recommended voltage of -4~V or higher to turn on this product.

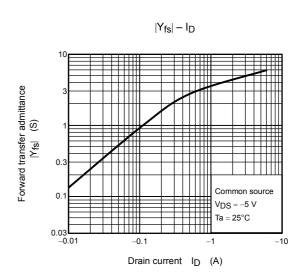


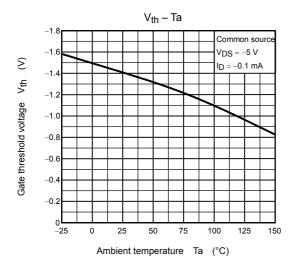


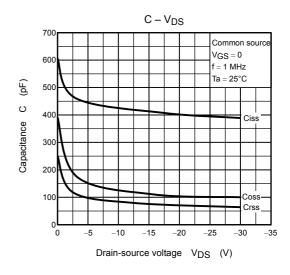


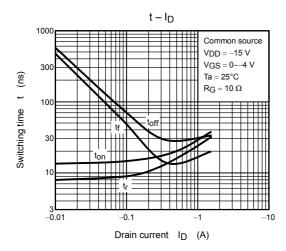


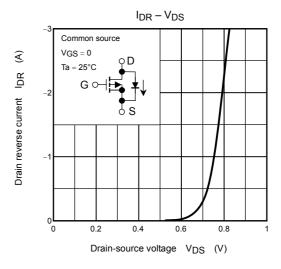


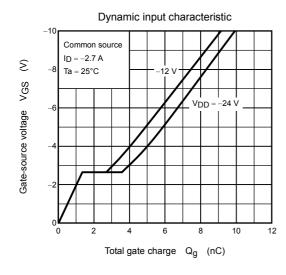


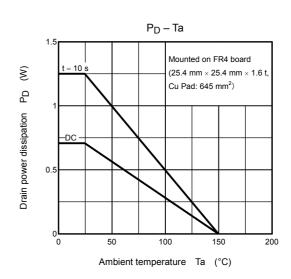




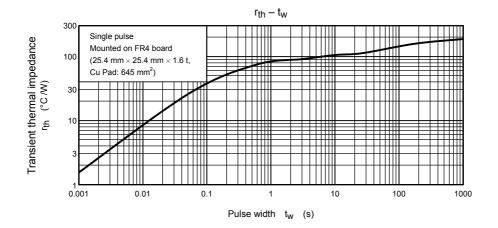


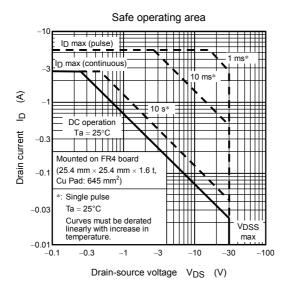






4





RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
 rights of the third parties which may result from its use. No license is granted by implication or otherwise under
 any intellectual property or other rights of TOSHIBA CORPORATION or others.

6

The information contained herein is subject to change without notice.